捷多邦,专业PCB打样工厂**SN54A0533**為N74AC533 OCTAL TRANSPARENT D-TYPE LATCHES WITH 3-STATE OUTPUTS

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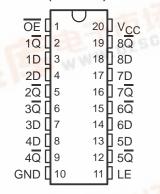
- 3-State Inverting Outputs Drive Bus Lines
 Directly
- Full Parallel Access for Loading
- EPIC ™ (Enhanced-Performance Implanted CMOS) 1-μm Process
- Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), Thin Shrink Small-Outline (PW), Ceramic Chip Carriers (FK) and Flatpacks (W), and Standard Plastic (N) and Ceramic (J) DIPs

description

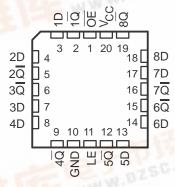
The 'AC533 are octal transparent D-type latches with 3-state outputs. When the latch-enable (LE) input is high, the \overline{Q} outputs follow the complements of the data (D) inputs. When LE is taken low, the \overline{Q} outputs are latched at the inverse logic levels set up at the D inputs.

A buffered output-enable (\overline{OE}) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or a high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without need for interface or pullup components.

SN54AC533 . . . J OR W PACKAGE SN74AC533 . . . DB, DW, N, OR PW PACKAGE (TOP VIEW)



SN54AC533 . . . FK PACKAGE (TOP VIEW)



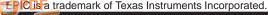
OE does not affect the internal operations of the latches. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

The SN54AC533 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74AC533 is characterized for operation from –40°C to 85°C.

FUNCTION TABLE (each latch)

	INPUTS		OUTPUT
OE	LE	D	Q
L	Н	Н	L
L	Н	L	Н
L	L	X	\overline{Q}_0
H	X	X	Z

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

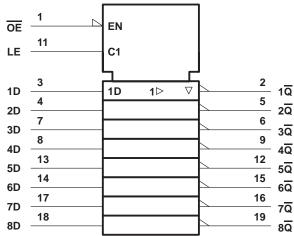




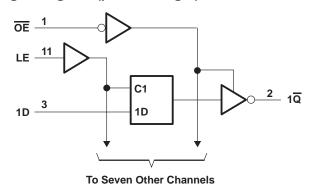
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logic symbol†



logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V _{CC}		–0.5 V to 7 V
Input voltage range, V _I (see Note 1)		$10.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Output voltage range, V _O (see Note 1)		$10.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Input clamp current, I_{IK} ($V_I < 0$ or $V_I > V_{CC}$)		±20 mA
Output clamp current, I _{OK} (V _O < 0 or V _O > V _{CC})		±20 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})		±50 mA
Continuous current through V _{CC} or GND		±200 mA
Maximum power dissipation at $T_A = 55^{\circ}$ C (in still air) (see Note 2	2): DB package	0.6 W
	DW package	1.6 W
	N package	1.3 W
	PW package	0.7 W
Storage temperature range, T _{stq}		–65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
 - 2. The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils, except for the N package, which has a trace length of zero.



[†]This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

recommended operating conditions (see Note 3)

			SN54A	SN54AC533		C533	LINIT
			MIN	MAX	MIN	MAX	UNIT
Vcc	Supply voltage		2	6	2	6	V
		V _{CC} = 3 V	2.1		2.1		
VIH	High-level input voltage	V _{CC} = 4.5 V	3.15		3.15		V
		V _{CC} = 5.5 V	3.85		3.85		
		V _{CC} = 3 V		0.9		0.9	
V_{IL}	Low-level input voltage	V _{CC} = 4.5 V		1.35		1.35	V
		V _{CC} = 5.5 V		1.65		1.65	
٧ _I	Input voltage		0	V _{CC}	0	VCC	V
٧o	Output voltage		&	VCC	0	VCC	V
		V _{CC} = 3 V	200	-12		-12	
lOH	High-level output current	V _{CC} = 4.5 V	N. S.	-24		-24	mA
		V _{CC} = 5.5 V		-24		-24	
		V _{CC} = 3 V		12		12	
lOL	Low-level output current	V _{CC} = 4.5 V		24		24	mA
		V _{CC} = 5.5 V		24		24	
Δt/Δν	Input transition rise or fall rate		0	8	0	8	ns/V
TA	Operating free-air temperature		-55	125	-40	85	°C

NOTE 3: Unused inputs must be held high or low to prevent them from floating.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V	T _A = 25°C			SN54A	C533	SN74A	UNIT	
PARAMETER	TEST CONDITIONS	VCC	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII
		3 V	2.9			2.9		2.9		
	I _{OH} = -50 μA	4.5 V	4.4			4.4		4.4		
Vou		5.5 V	5.4			5.4		5.4		V
VOH	I _{OH} = -12 mA	3 V	2.56			2.4		2.46		V
	I _{OH} = -24 mA	4.5 V	3.86			3.7	EM	3.76		
	IOH = -24 IIIA	5.5 V	4.86			4.7	S.	4.76		
		3 V			0.1	4	0.1		0.1	V
	I _{OL} = 50 μA	4.5 V			0.1	\\ \(\)	0.1		0.1	
Vo.		5.5 V			0.1	70	0.1		0.1	
VOL	I _{OL} = 12 mA	3 V			0.36	D _Y	0.5		0.44	V
	I _{OL} = 24 mA	4.5 V			0.36	y	0.5		0.44	
	10L = 24 IIIA	5.5 V			0.36		0.5		0.44	
loz	$V_O = V_{CC}$ or GND	5.5 V			±0.25		±5		±2.5	μΑ
lį	V _I = V _{CC} or GND	5.5 V			±0.1		±1		±1	μΑ
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			4		80		40	μΑ
C _i	V _I = V _{CC} or GND	5 V		4.5						pF



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timing requirements over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

		T _A = 25°C		SN54AC533		SN74AC533		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	UNIT
t _W	Pulse duration, LE high	6		8	EN	6.5		ns
t _{su}	Setup time, data before LE↓	5.5		7.5	EL.	6		ns
t _h	Hold time, data after LE↓	1.5		2.5	ζ.	1		ns

timing requirements over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

		T _A = 25°C		SN54AC533	SN74AC533		UNIT
		MIN	MAX	MIN MAX	MIN	MAX	UNIT
t _W	Pulse duration, LE high	4.5		6.55	5		ns
t _{su}	Setup time, data before LE↓	4		6	4.5		ns
th	Hold time, data after LE↓	1.5		2.5	1		ns

switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

DADAMETED	PARAMETER FROM TO		T _A = 2	25°C	SN54A	C533	SN74A	C533	UNIT
FARAMETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	ONIT
^t PLH	D	Ια	2	14	1	17.5	1.5	16	ns
^t PHL	Б		2	13	1	16	1.5	14.5	115
t _{PLH}	LE	Ια	2	14.5	1	18	1.5	16.5	ns
^t PHL	LE	Q	2	13	1,	16	1.5	14.5	115
^t PZH	<u>OE</u>	ы	2	12.5	37)	15.5	1.5	14	20
^t PZL	OE	Q	2	12.5	001	15.5	1.5	14	ns
^t PHZ	ŌĒ	Ια	2	13	2 1	16	1.5	14.5	ns
t _{PLZ}	OE	ά	2	13	1	16	1.5	14.5	115

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

<u> </u>	•									
PARAMETER	FROM TO		T _A = 1	25°C	SN54A	C533	SN74A	C533	UNIT	
PARAMETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	UNIT	
^t PLH	D	Q	2	10	1	12.5	1.5	11	no	
^t PHL	1 "	Q	2	9.5	1	12	1.5	10.5	ns	
^t PLH	LE	Q	2	10.5	1	13	1.5	11.5	no	
^t PHL		Q	2	10	1,4	13	1.5	11	ns	
^t PZH	- OE	ā	2	9.5	(1)	12	1.5	10.5	ns	
^t PZL] OE	Q	2	9.5	Q1	12	1.5	10.5	115	
^t PHZ	ŌĒ	Q	2	10	2 1	12.5	1.5	11	nc	
t _{PLZ}]	l q	l q	2	10	1	12.5	1.5	11	ns

operating characteristics, V_{CC} = 5 V, T_A = 25°C

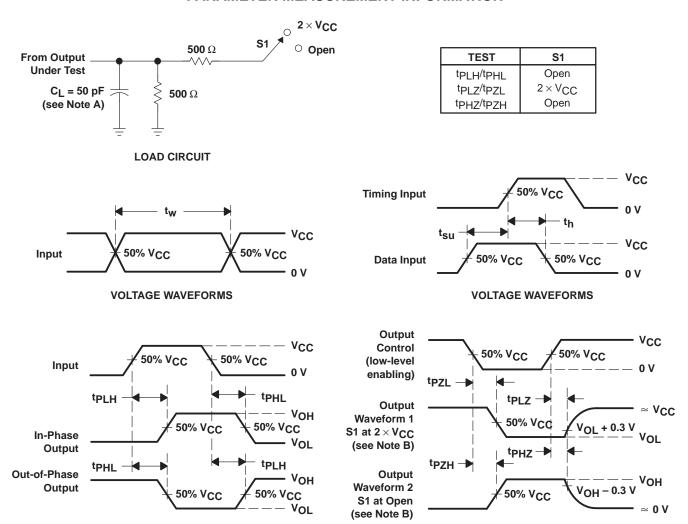
	PARAMETER	TEST CONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	$C_L = 50 \text{ pF}, f = 1 \text{ MHz}$	40	pF



VOLTAGE WAVEFORMS

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PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_I includes probe and jig capacitance.

VOLTAGE WAVEFORMS

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_f \leq$ 2.5 ns. $t_f \leq$ 2.5 ns.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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